Amplifier Transistors

Voltage and Current are Negative for PNP Transistors

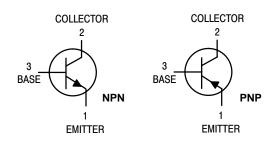
Features

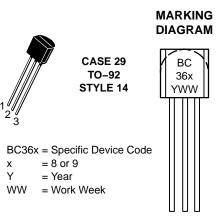
• Pb–Free Packages are Available*



ON Semiconductor[®]

http://onsemi.com





ORDERING INFORMATION

Device	Package	Shipping [†]
BC368	TO-92	5000 Units/Box
BC368ZL1	TO-92	2000/Ammo Pack
BC368ZL1G	TO–92 (Pb–Free)	2000/Ammo Pack
BC369	TO-92	5000 Units/Box
BC369ZL1	TO-92	2000/Ammo Pack
BC369ZL1G	TO–92 (Pb–Free)	2000/Ammo Pack

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	20	Vdc
Collector – Emitter Voltage	V _{CES}	25	Vdc
Emitter-Base Voltage	V_{EBO}	5.0	Vdc
Collector Current – Continuous	۱ _C	1.0	Adc
Total Device Dissipation @ T _A = 25°C	PD	625	mW
Derate above 25°C		5.0	mW/°C
Total Device Dissipation @ T _C = 25°C	PD	1.5	Watt
Derate above 25°C		12	mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	–55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

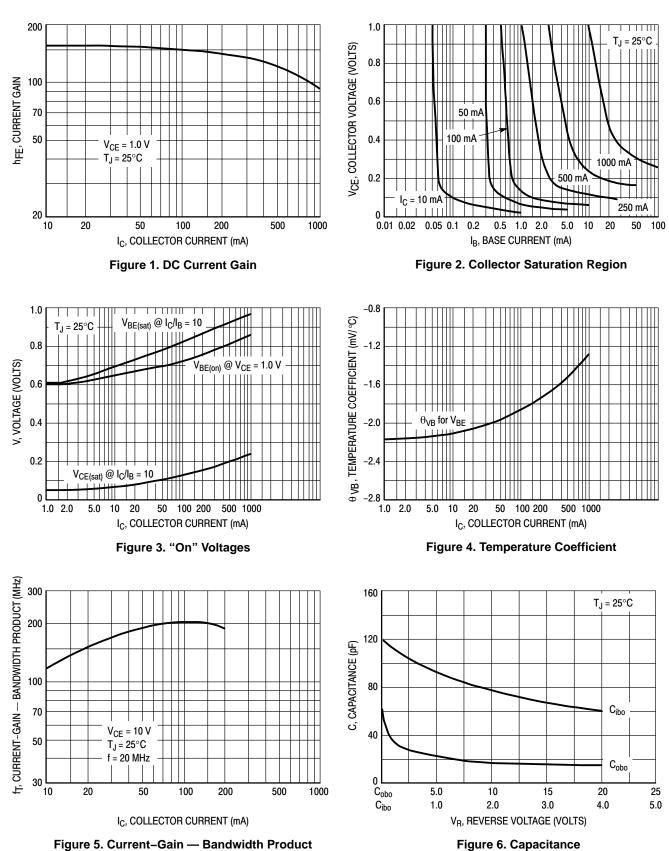
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Ambient	R_{\thetaJA}	200	°C/W
Thermal Resistance, Junction–to–Case	$R_{\theta JC}$	83.3	°C/W

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

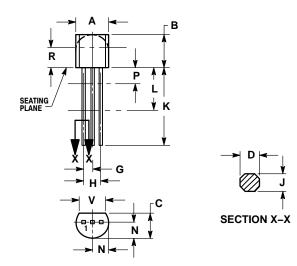
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage ($I_C = 10 \text{ mA}, I_B = 0$)	V _{(BR)CEO}	20	-	-	Vdc
Collector – Base Breakdown Voltage $(I_C = 100 \ \mu A, I_E = 0)$	V _{(BR)CBO}	25	-	-	Vdc
Emitter – Base Breakdown Voltage $(I_E = 100 \ \mu A, I_C = 0)$	V _{(BR)EBO}	5.0	-	-	Vdc
Collector Cutoff Current $(V_{CB} = 25 \text{ V}, I_E = 0)$ $(V_{CB} = 25 \text{ V}, I_E = 0, T_J = 150^{\circ}\text{C})$	I _{CBO}	-		10 1.0	μAdc mAdc
Emitter Cutoff Current ($V_{EB} = 5.0 \text{ V}, I_C = 0$)	I _{EBO}	-	-	10	μAdc
ON CHARACTERISTICS					-
(OE) O)	h _{FE} 68, 369 368–25	50 85 170 60	- - - -	- 375 375 -	_
Bandwidth Product ($I_C = 10 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$, f = 20 MHz)	f _T	65	-	-	MHz
Collector-Emitter Saturation Voltage ($I_C = 1.0 \text{ A}, I_B = 100 \text{ mA}$)	V _{CE(sat)}	-	-	0.5	V
Base–Emitter On Voltage ($I_C = 1.0 \text{ A}$, $V_{CE} = 1.0 \text{ V}$)	V _{BE(on)}	-	-	1.0	V



PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL**



NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. Controlling dimension: Inch. Contour of Package Beyond Dimension R Is uncontrolled.
- 2 3.
- 4.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
Ν	0.080	0.105	2.04	2.66	
Ρ		0.100		2.54	
R	0.115		2.93		
٧	0.135		3.43		
STYLE 14: PIN 1. EMITTER					

COLLECTOR 2 3. BASE

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